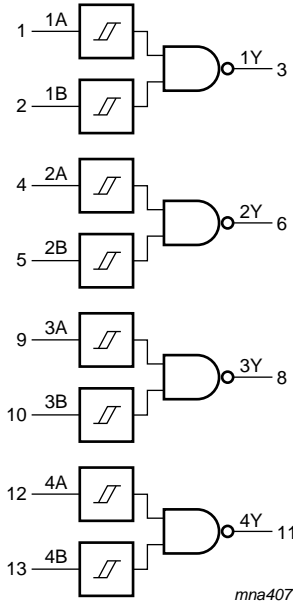


4. Ordering information

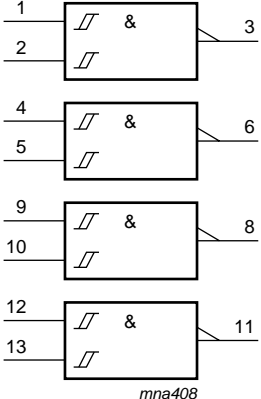
Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC132N	−40 °C to +125 °C	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1
74HCT132N				
74HC132D	−40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1
74HCT132D				
74HC132DB	−40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads; body width 5.3 mm	SOT337-1
74HCT132DB				
74HC132PW	−40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1
74HCT132PW				

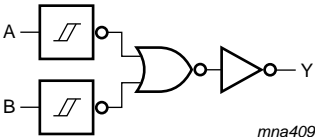
5. Functional diagram



**Fig 1. Logic symbol**



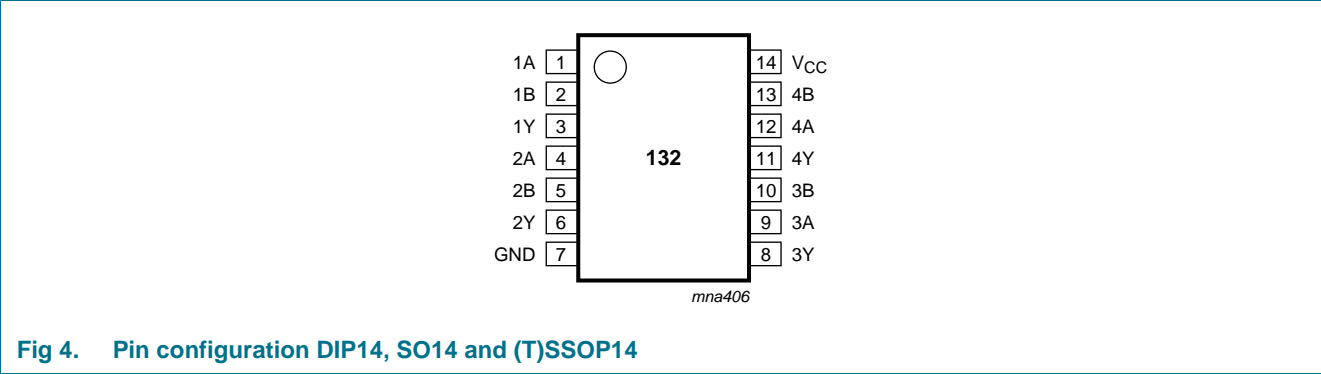
**Fig 2. IEC logic symbol**



**Fig 3. Logic diagram (one Schmitt trigger)**

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1A to 4A	1, 4, 9, 12	data input
1B to 4B	2, 5, 10, 13	data input
1Y to 4Y	3, 6, 8, 11	data output
GND	7	ground (0 V)
V <sub>CC</sub>	14	supply voltage

7. Functional description

Table 3. Function table<sup>[1]</sup>

Input		Output
nA	nB	nY
L	L	H
L	H	H
H	L	H
H	H	L

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

## 8. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7	V
$I_{IK}$	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$	[1] -	$\pm 20$	mA
$I_{OK}$	output clamping current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$	[1] -	$\pm 20$	mA
$I_O$	output current	$-0.5\text{ V} < V_O < V_{CC} + 0.5\text{ V}$	-	$\pm 25$	mA
$I_{CC}$	supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation		[2]		
	DIP14 package		-	750	mW
	SO14, and (T)SSOP14 packages		-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For DIP14 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

For SO14 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

For (T)SSOP14 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

## 9. Recommended operating conditions

**Table 5. Recommended operating conditions**

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC132			74HCT132			Unit
			Min	Typ	Max	Min	Typ	Max	
$V_{CC}$	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
$V_I$	input voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V
$V_O$	output voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V
$T_{amb}$	ambient temperature		-40	+25	+125	-40	+25	+125	°C

## 10. Static characteristics

**Table 6. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
74HC132										
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T–</sub>								
		I <sub>O</sub> = –20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = –20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = –20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I <sub>O</sub> = –4.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I <sub>O</sub> = –5.2 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T–</sub>								
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	2.0	-	20	-	40	μA
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT132										
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T–</sub> ; V <sub>CC</sub> = 4.5 V								
		I <sub>O</sub> = –20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = –4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T–</sub> ; V <sub>CC</sub> = 4.5 V								
		I <sub>O</sub> = 20 μA;	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA;	-	0.15	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	2.0	-	20	-	40	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; V <sub>I</sub> = V <sub>CC</sub> – 2.1 V; I <sub>O</sub> = 0 A; other inputs at V <sub>CC</sub> or GND; V <sub>CC</sub> = 4.5 V to 5.5 V	-	30	108	-	135	-	147	μA
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF

## 11. Dynamic characteristics

**Table 7. Dynamic characteristics**

$GND = 0\text{ V}$ ;  $C_L = 50\text{ pF}$ ; for load circuit see [Figure 6](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +125 °C		Unit
			Min	Typ	Max	Max (85 °C)	Max (125 °C)	
74HC132								
t <sub>pd</sub>	propagation delay	nA, nB to nY; see <a href="#">Figure 5</a> <a href="#">[1]</a>						
		V <sub>CC</sub> = 2.0 V	-	36	125	155	190	ns
		V <sub>CC</sub> = 4.5 V	-	13	25	31	38	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	11	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	10	21	26	32	ns
t <sub>t</sub>	transition time	see <a href="#">Figure 5</a> <a href="#">[2]</a>						
		V <sub>CC</sub> = 2.0 V	-	19	75	95	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	19	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	16	19	ns
C <sub>PD</sub>	power dissipation capacitance	per package; V <sub>I</sub> = GND to V <sub>CC</sub> <a href="#">[3]</a>	-	24	-	-	-	pF
74HCT132								
t <sub>pd</sub>	propagation delay	nA, nB to nY; see <a href="#">Figure 5</a> <a href="#">[1]</a>						
		V <sub>CC</sub> = 4.5 V	-	20	33	41	50	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	17	-	-	-	ns
t <sub>t</sub>	transition time	V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 5</a> <a href="#">[2]</a>	-	7	15	19	22	ns
C <sub>PD</sub>	power dissipation capacitance	per package; V <sub>I</sub> = GND to V <sub>CC</sub> – 1.5 V <a href="#">[3]</a>	-	20	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

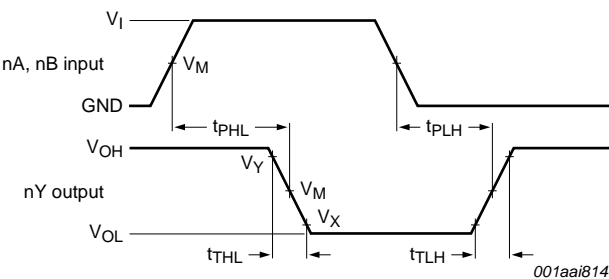
$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

12. Waveforms

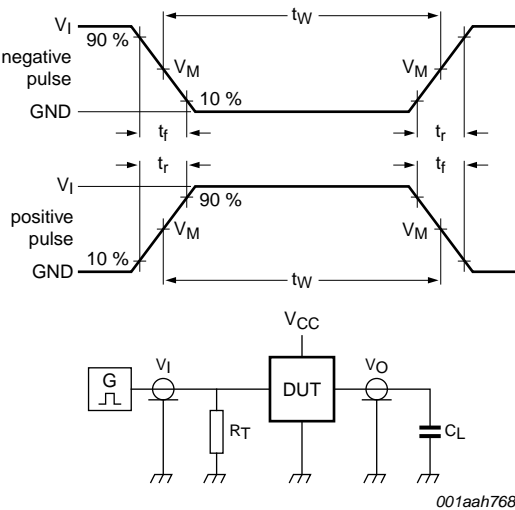


Measurement points are given in [Table 8](#).  
 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

Fig 5. Input to output propagation delays

Table 8. Measurement points

Type	Input	Output		
	$V_M$	$V_M$	$V_X$	$V_Y$
74HC132	$0.5V_{CC}$	$0.5V_{CC}$	$0.1V_{CC}$	$0.9V_{CC}$
74HCT132	1.3 V	1.3 V	$0.1V_{CC}$	$0.9V_{CC}$



Test data is given in [Table 9](#).  
Definitions test circuit:  
 $R_T$  = termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.  
 $C_L$  = load capacitance including jig and probe capacitance.

Fig 6. Load circuitry for measuring switching times

Table 9. Test data

Type	Input		Load	Test
	$V_I$	$t_r, t_f$	$C_L$	
74HC132	$V_{CC}$	6.0 ns	15 pF, 50 pF	$t_{PLH}, t_{PHL}$
74HCT132	3.0 V	6.0 ns	15 pF, 50 pF	$t_{PLH}, t_{PHL}$

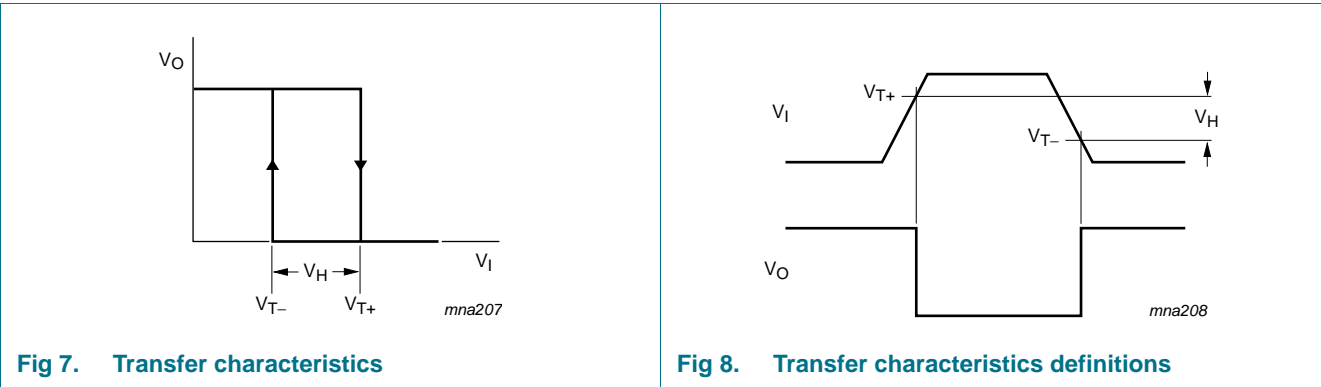
13. Transfer characteristics

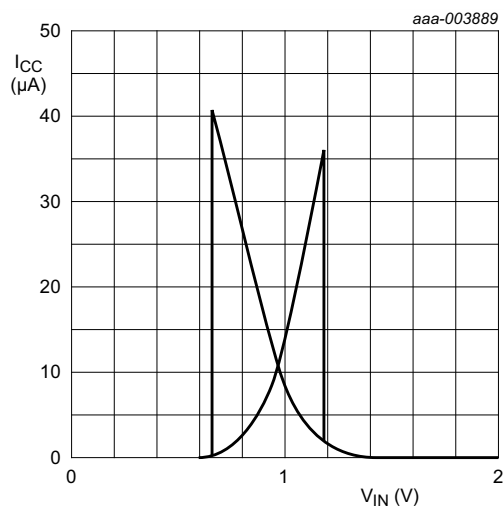
Table 10. Transfer characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); see [Figure 7](#) and [Figure 8](#).

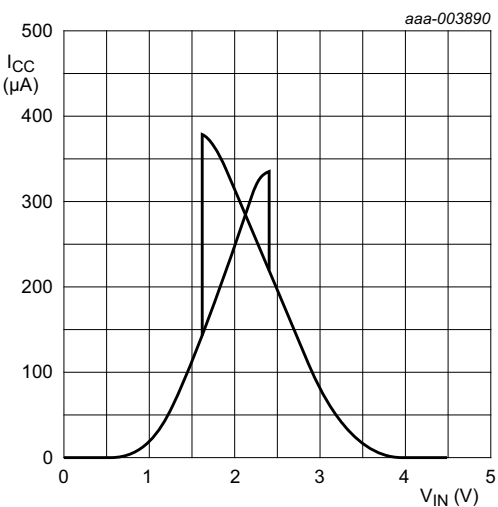
Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = −40 °C to +85 °C		T <sub>amb</sub> = −40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
74HC132										
V <sub>T+</sub>	positive-going threshold voltage	V <sub>CC</sub> = 2.0 V	0.7	1.18	1.5	0.7	1.5	0.7	1.5	V
		V <sub>CC</sub> = 4.5 V	1.7	2.38	3.15	1.7	3.15	1.7	3.15	V
		V <sub>CC</sub> = 6.0 V	2.1	3.14	4.2	2.1	4.2	2.1	4.2	V
V <sub>T−</sub>	negative-going threshold voltage	V <sub>CC</sub> = 2.0 V	0.3	0.63	1.0	0.3	1.0	0.3	1.0	V
		V <sub>CC</sub> = 4.5 V	0.9	1.67	2.2	0.9	2.2	0.9	2.2	V
		V <sub>CC</sub> = 6.0 V	1.2	2.26	3.0	1.2	3.0	1.2	3.0	V
V <sub>H</sub>	hysteresis voltage	V <sub>CC</sub> = 2.0 V	0.2	0.55	1.0	0.2	1.0	0.2	1.0	V
		V <sub>CC</sub> = 4.5 V	0.4	0.71	1.4	0.4	1.4	0.4	1.4	V
		V <sub>CC</sub> = 6.0 V	0.6	0.88	1.6	0.6	1.6	0.6	1.6	V
74HCT132										
V <sub>T+</sub>	positive-going threshold voltage	V <sub>CC</sub> = 4.5 V	1.2	1.41	1.9	1.2	1.9	1.2	1.9	V
		V <sub>CC</sub> = 5.5 V	1.4	1.59	2.1	1.4	2.1	1.4	2.1	V
V <sub>T−</sub>	negative-going threshold voltage	V <sub>CC</sub> = 4.5 V	0.5	0.85	1.2	0.5	1.2	0.5	1.2	V
		V <sub>CC</sub> = 5.5 V	0.6	0.99	1.4	0.6	1.4	0.6	1.4	V
V <sub>H</sub>	hysteresis voltage	V <sub>CC</sub> = 4.5 V	0.4	0.56	-	0.4	-	0.4	-	V
		V <sub>CC</sub> = 5.5 V	0.4	0.60	-	0.4	-	0.4	-	V

14. Transfer characteristics waveforms

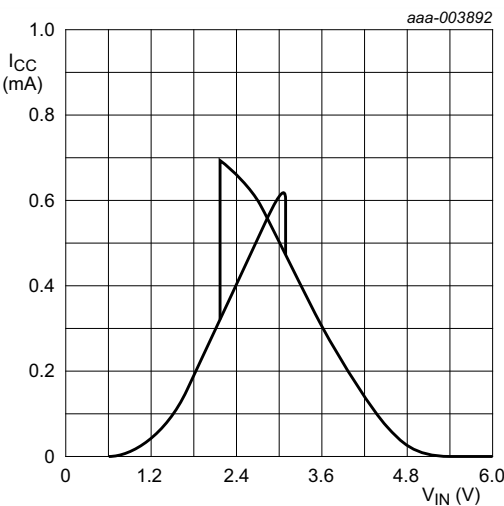




a.  $V_{CC} = 2.0\text{ V}$



b.  $V_{CC} = 4.5\text{ V}$



c.  $V_{CC} = 6.0\text{ V}$

Fig 9. Typical 74HC132 transfer characteristics



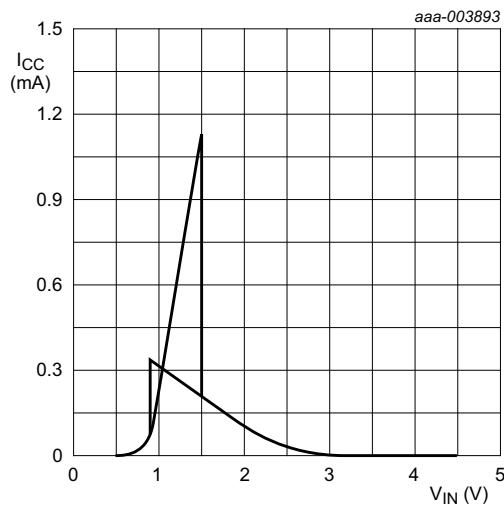
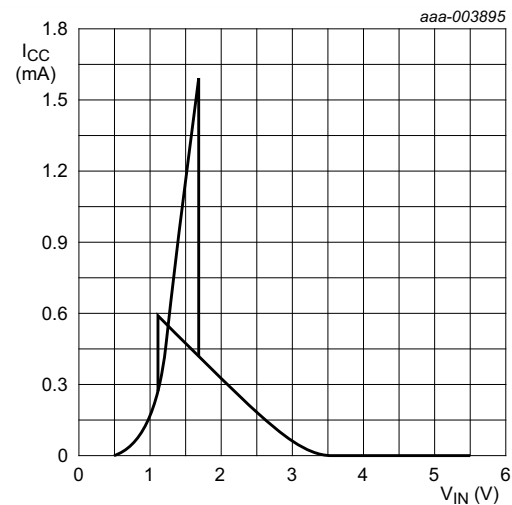
a.  $V_{CC} = 4.5 \text{ V}$ b.  $V_{CC} = 5.5 \text{ V}$ 

Fig 10. Typical 74HCT132 transfer characteristics

## 15. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$$P_{\text{add}} = f_i \times (t_r \times \Delta I_{CC(\text{AV})} + t_f \times \Delta I_{CC(\text{AV})}) \times V_{CC} \text{ where:}$$

$P_{\text{add}}$  = additional power dissipation ( $\mu\text{W}$ );

$f_i$  = input frequency (MHz);

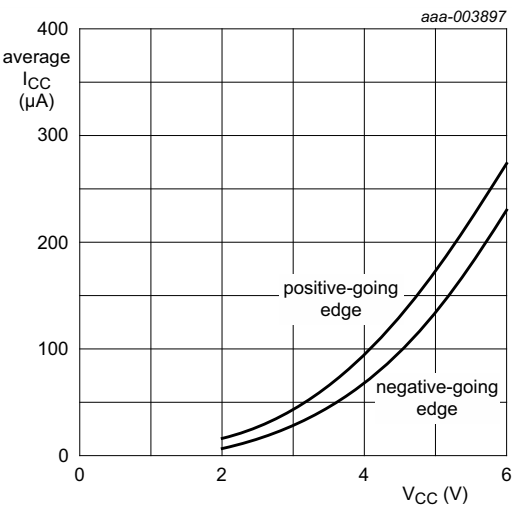
$t_r$  = rise time (ns); 10 % to 90 %;

$t_f$  = fall time (ns); 90 % to 10 %;

$\Delta I_{CC(\text{AV})}$  = average additional supply current ( $\mu\text{A}$ ).

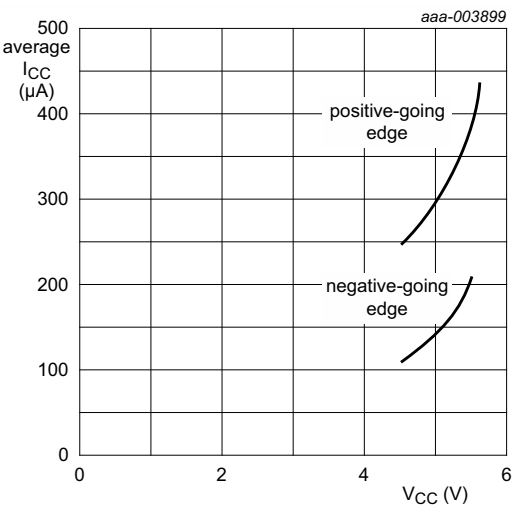
Average  $\Delta I_{CC(\text{AV})}$  differs with positive or negative input transitions, as shown in [Figure 11](#) and [Figure 12](#).

An example of a relaxation circuit using the 74HC132; 74HCT132 is shown in [Figure 13](#).



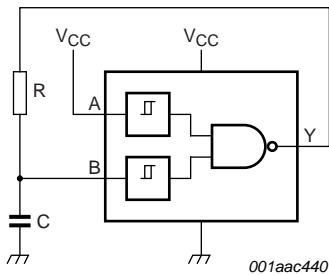
- (1) Positive-going edge.
- (2) Negative-going edge.

Fig 11. Average additional supply current as a function of  $V_{CC}$  for 74HC132; linear change of  $V_I$  between  $0.1V_{CC}$  to  $0.9V_{CC}$ .



- (1) Positive-going edge.
- (2) Negative-going edge.

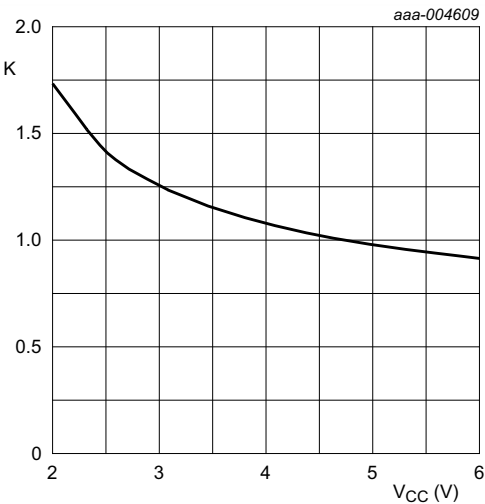
Fig 12. Average additional supply current as a function of  $V_{CC}$  for 74HCT132; linear change of  $V_I$  between  $0.1V_{CC}$  to  $0.9V_{CC}$ .



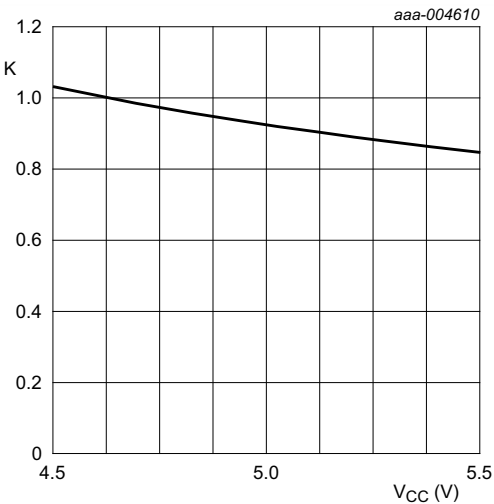
For 74HC132 and 74HCT132:  $f = \frac{1}{T} \approx \frac{1}{K \times RC}$

For K-factor, see [Figure 14](#)

Fig 13. Relaxation oscillator



K-factor for 74HC132



K-factor for 74HCT132

Fig 14. Typical K-factor for relaxation oscillator

16. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1

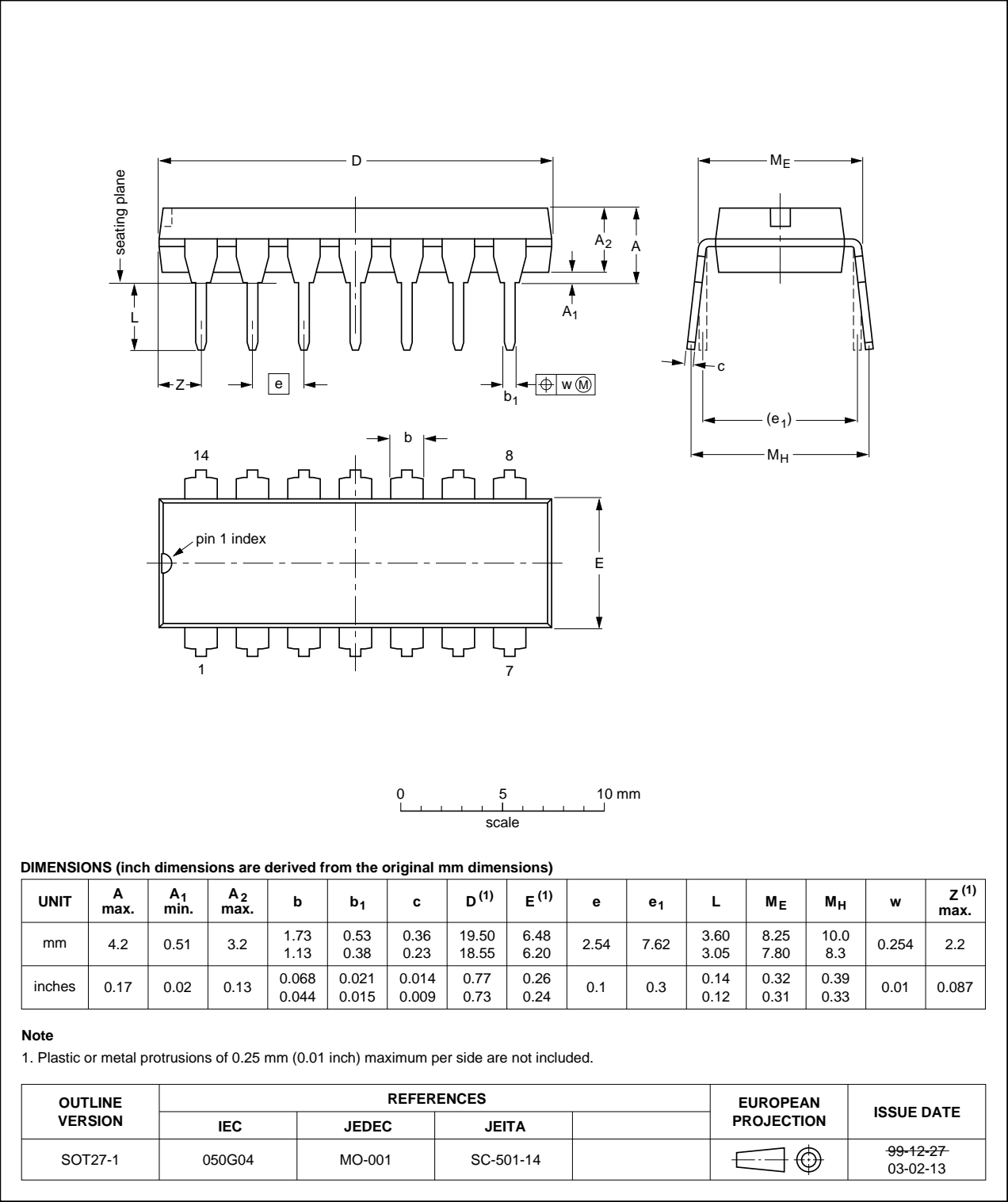


Fig 15. Package outline SOT27-1 (DIP14)

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

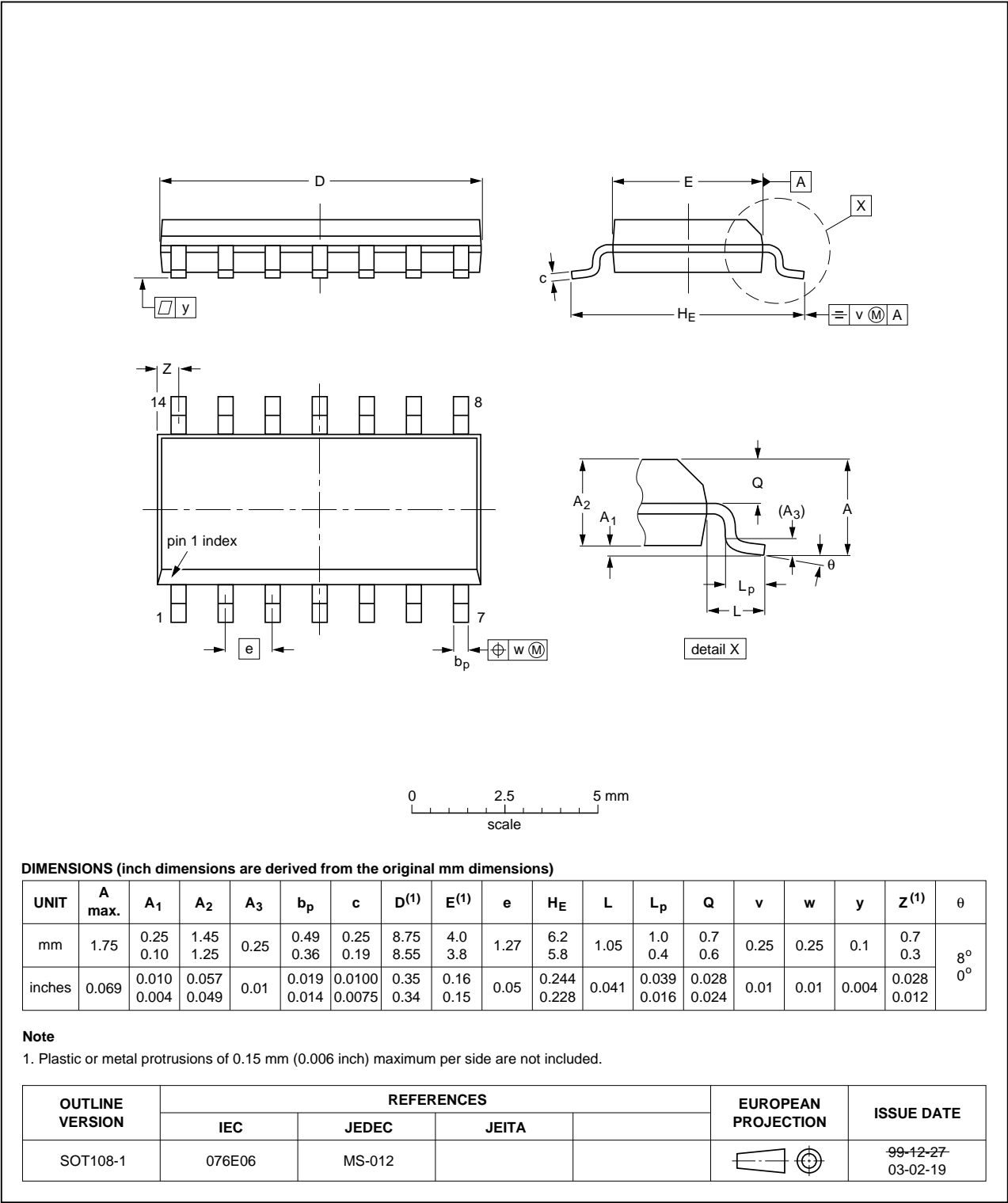


Fig 16. Package outline SOT108-1 (SO14)

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

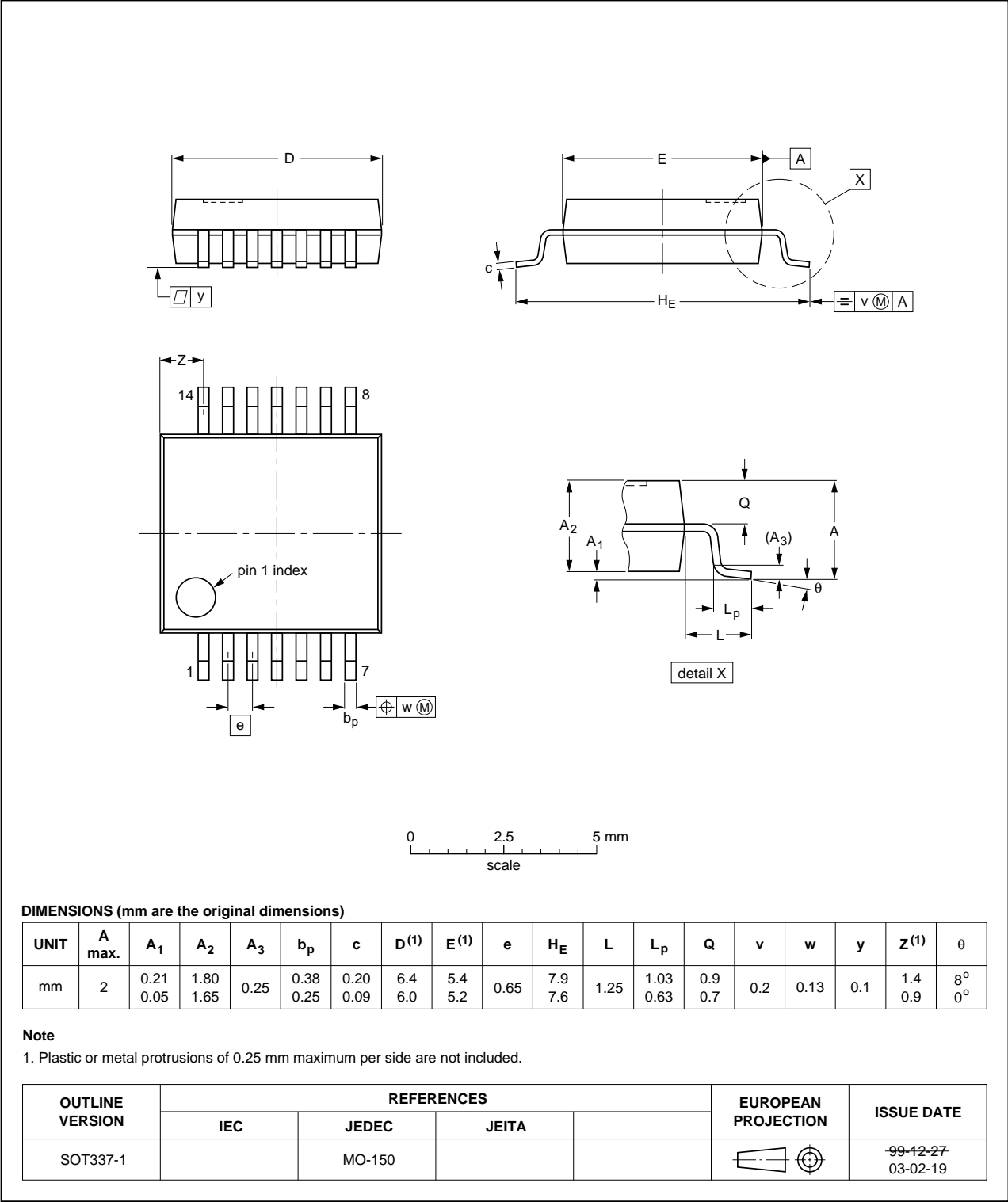


Fig 17. Package outline SOT337-1 (SSOP14)

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1

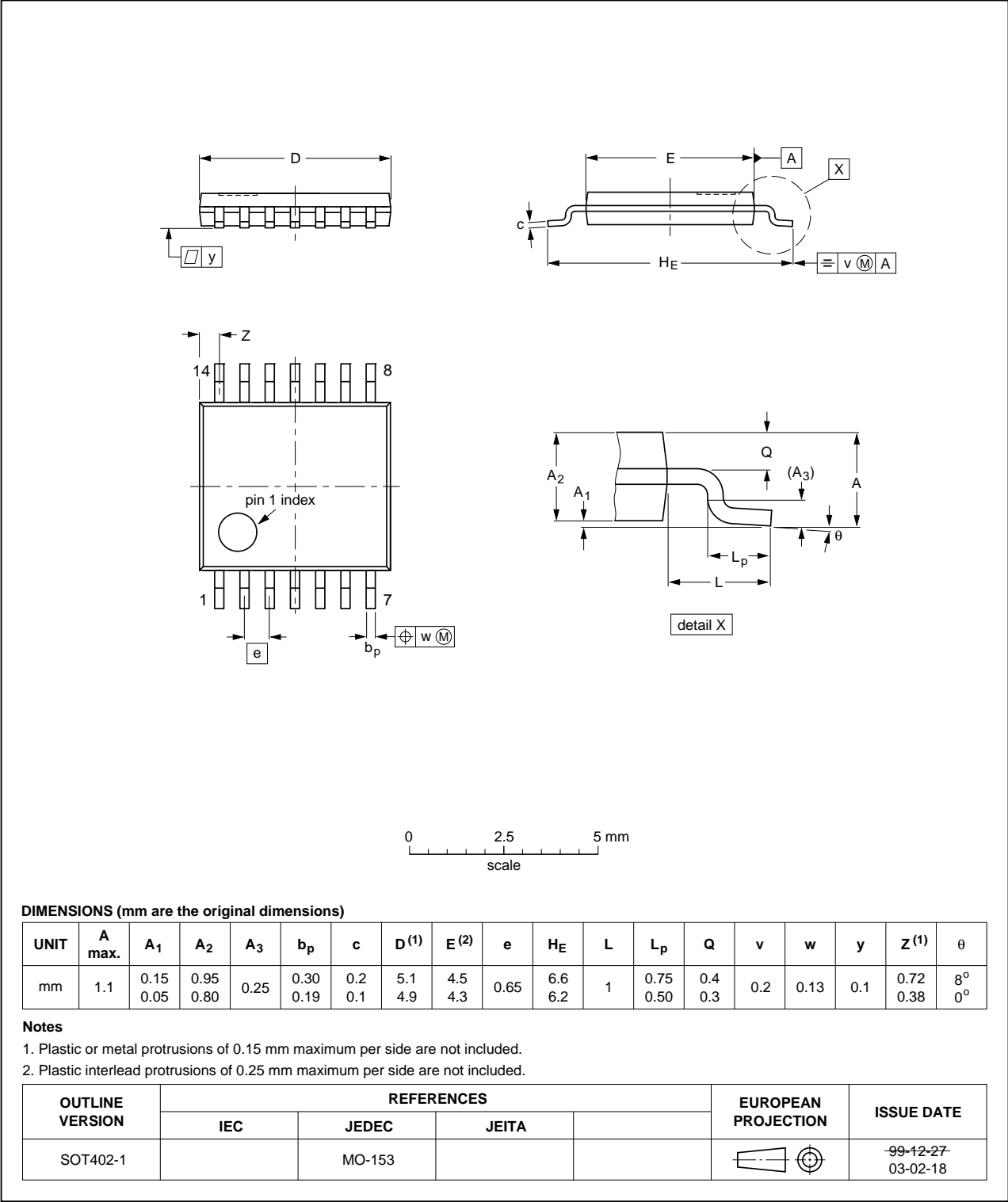


Fig 18. Package outline SOT402-1 (TSSOP14)

## 17. Abbreviations

Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MM	Machine Model
TTL	Transistor-Transistor Logic

## 18. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT132 v.3	20120830	Product data sheet	-	74HC_HCT132_CNV v.2
Modifications:	<ul style="list-style-type: none"><li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li><li>• Legal texts have been adapted to the new company name where appropriate.</li><li>• <a href="#">Figure 14</a> added (typical K-factor for relaxation oscillator).</li></ul>			
74HC_HCT132_CNV v.2	19970826	Product specification	-	-



## 19. Legal information

### 19.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

### 19.2 Definitions

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